

**THE INVESTIGATION OF POLYTHERMIC SECTION
Ga₂S₃-(Y₂O₂S)_{0.50}(Tb₂O₂S)_{0.50} OF QUASI-TERNARY SYSTEM
«Y₂O₂S – Ga₂S₃ – Tb₂O₂S»**

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At present time oxysulfides of lanthanoids and solid solutions on their basis are used as the initial substances for obtaining optic materials transparent in the wide field of spectrum, as well as in luminophores and pigments. This thesis reports the information regarding one of the investigated non-quasi-polymeric sections for determining the coordinates of the initial crystallization spaces, isotherms, and monovariant curves in the *quasi-ternary system* (Ga₂S₃-(Y₂O₂S)_{0.50}(Tb₂O₂S)_{0.50}). The samples in the section were synthesized by a ceramic method from the initial components and investigated through physico-chemical methods (DTA, RFA, MQ, measurement of microhardness, density) after processing at 1150K temperature. Based on the findings obtained, the phase diagram of non-quasi-binary section Ga₂S₃-(Y₂O₂S)_{0.50}(Tb₂O₂S)_{0.50} is set below. Liquidus in the phase diagram of the section Ga₂S₃ – (Y₂O₂S)_{0.50}(Tb₂O₂S)_{0.50}, is composed of two branches intersecting where the section crosses the monovariant curve at the intersection point and reflecting in the initial crystallization region γ (Ga₂S₃ and α [(Y₂O₂S)_{1-x}(Tb₂O₂S)_x] of solid solutions. Hence, in Ga₂S₃-rich space, as Ga₂S₃ – (Y₂O₂S)_{0.50}(Tb₂O₂S)_{0.50} crosses the monovariant curve, the initial crystallization space γ (Ga₂S₃) is reflected in the liquidus. The binary crystallization $m+\alpha+\gamma$ reflects a wider density interval in the phase diagram of the section. Hence, the process starts with K1 (TOP curves) and ends with K1¹ (Bottom curves). In the subsolidus of non-quasi-binary section $\alpha+\beta$ mixture decomposes (breakdowns) at 300K. Thus, Y₂O₂S - Ga₂S₃ - Tb₂O₂S is the quasi-ternary system of the above-mentioned section of the non-quasi-binary system. The *cathodoluminescence properties* of (Ga₂S₃)_{1-x}(Y₂O₂S)_{x-y}(Tb₂O₂S)_y composition have been studied from the region where the applied section intersects the Ga₂S₃-rich ternary solid solutions space. To measure a relative lighting in the samples, an electron ray tube connected to an electron-optical system (EOS) with an oxide cathode has been used as a cathode excitement. The electron flow energy is 200 keV. As can be seen from the spectrum, several groups of narrow band radiation ⁵D₃→⁷F₆ (385 nm), ⁵D₃→⁷F₅ (420 nm), ⁵D₃→⁷F₄ (440 nm), ⁵D₃→⁷F₃ (462 nm), ⁵D₃→⁷F₂ (470 nm), ⁵D₄→⁷F₆ (500 nm), ⁵D₄→⁷F₄ (583 nm), ⁵D₄→⁷F₃ (625 nm), were observed in the wavelength of 350 ÷ 620 nm. This is due to the transition from ⁵D₃ and ⁵D level to the inner ⁷F_j stark level of Tb³⁺ ion. (Ga₂S₃)_{1-x}(Y₂O₂S)_{x-y}(Tb₂O₂S)_y solid solutions can be used in the production of osillographs, TV screens, electron microscopes, and other radiation devices, as *cathodoluminescence* material emitting the green color.